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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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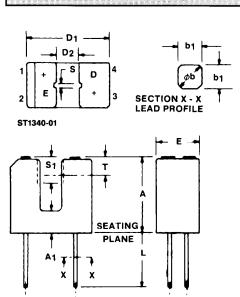






H22A4/5/6

PACKAGE DIMENSIONS

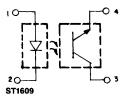


SYMBOL	MILLIMETERS		INC	NOTES	
OTVIDOL	MIN.	MAX.	MIN.	MAX.	INOTES
Α	10.7	11.0	.422	.433	
Α,	3.0	3.2	.119	.125	
®b	.600	.750	.024	.030	2
b₁	.50 N	IOM.	.020	NOM.	2
D,	11.6	12.0	.457	.472	
D ₂	3.0	3.3	.119	.129	
e,	6.9	7.5	.272	.295	
e ₂	2.3	2.8	.091	.110	
E	6.15	6.35	.243	.249	
L	8.00		.315		
S	.85	1.0	.034	.039	
S,	3.45	3.75	.136	.147	
T	2.6 N	IOM.	.103	NOM.	3

NOTES:

- 1. INCH DIMENSIONS ARE DERIVED FROM MILLIMETERS.
- FOUR LEADS. LEAD CROSS SECTION IS CONTROLLED BETWEEN 1.27mm (.050") FROM SEATING PLANE AND THE END OF THE LEADS.
- 3. THE SENSING AREA IS DEFINED BY THE "S" DIMENSION AND BY DIMENSION "T" ±0.75mm (±.030 INCH).

PACKAGE OUTLINE



ST1340-02

DESCRIPTION

The H22A Slotted Optical Switch is a gallium arsenide light emitting diode coupled to a silicon photodarlington in a plastic housing. The packaging system is designed to optimize the mechanical resolution, coupling efficiency, ambient light rejection, cost and reliability. The gap in the housing provides a means of interrupting the signal with an opaque material, switching the output from an "ON" to an "OFF" state.

FEATURES

- Opaque housing
- Low cost
- .035" apertures
- High I_{C(ON)}



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C Uni	ess Otherwise Specified)
Storage Temperature	
Operating Temperature	
Lead Temperature (Iron)	
Lead Temperature (Flow)	260°C for 10 sec. (3,4)
INPUT DIODE	
Continuous Forward Current	
Reverse Voltage	
Power Dissipation	Iou mw
OUTPUT TRANSISTOR	
Collector-Emitter Voltage	
Emitter-Collector Voltage	
Power Dissipation	150 mW ⁽²⁾

ELECTRICAL CHAP	RACTERIST	TICS (Γ _A = 25°C Unie	ess Other	wise Specific	ed)
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
Forward Voltage	V_{F}	_		1.7	٧	$I_F = 60 \text{ mA}$
Reverse Breakdown Voltage	V _R	6.0		_	٧	$I_R = 10 \mu A$
Reverse Leakage Current	I _R	_		1.0	μΑ	V _R = 3 V
OUTPUT TRANSISTOR						
Emitter-Collector Breakdown	BV_{ECO}	6			V	$I_E = 100 \ \mu A, Ee = 0$
Collector-Emitter Breakdown	BV _{CEO}	55		_	٧	I _c = 1 mA, Ee = 0
Collector-Emitter Leakage	I _{CEO}	_		100	nA	V _{CE} = 45 V, Ee = 0
COUPLED						
On-State Collector Current	I _{C(ON)}		See page 3.		mA	
Saturation Voltage	V _{CE(SAT)}		See page 3.		٧	
Turn-On Time	t _{on}		See page 3.		μS	
Turn-Off Time	t _{off}		See page 3.		μS	

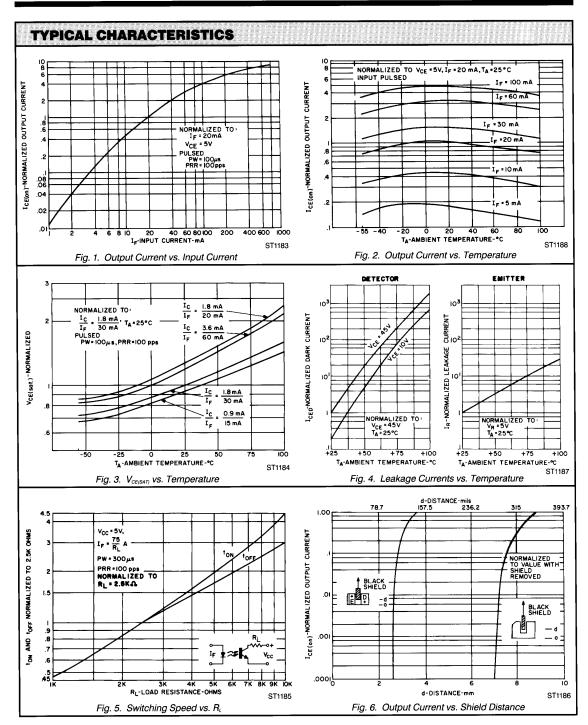
NOTES

- Derate power dissipation linearly 1.33 mW/°C above 25°C.
 Derate power dissipation linearly 2.00 mW/°C above 25°C.
 RMA flux is recommended.
- Methanol or Isopropyl alcohols are recommended as cleaning agents.
 Soldering iron tip 1/6" (1.6 mm) from housing.



PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
ON-STATE COLLECTOR	CURRENT				·-	
H22A4	I _{C(ON)}	0.15	_	_	mA	$I_F = 5$ mA, $V_{CE} = 5$ V
H22A5	I _{C(ON)}	0.30	_	_	mA	$I_F = 5mA$, $V_{CE} = 5V$
H22A6	I _{C(ON)}	0.60	_		mA	$I_{\scriptscriptstyle F}=5 { m mA}, V_{\scriptscriptstyle { m CE}}=5 { m V}$
H22A4	I _{C(ON)}	1.0			mA	$I_F = 20$ mA, $V_{CE} = 5$ V
H22A5	I _{C(ON)}	2.0	_	_	mA	$I_F = 20 \text{mA}, V_{CE} = 5 \text{V}$
H22A6	(C(ON)	4.0			mA	$I_{\scriptscriptstyle F}=20\text{mA},V_{\scriptscriptstyle CE}=5V$
H22A4	I _{C(ON)}	1.9			mA	$I_F = 30$ mA, $V_{CE} = 5$ V
H22A5	I _{C(ON)}	3.0		_	mA	$I_F = 30$ mA, $V_{CE} = 5$ V
H22A6	I _{C(ON)}	5.5			mA	$I_F = 30\text{mA}, V_{CE} = 5V$
SATURATION VOLTAGE			****			
H22A5	$V_{\text{CE(SAT)}}$		_	0.40	٧	$I_F = 20 \text{mA}, I_C = 1.8 \text{mA}$
H22A6	V _{CE(SAT)}			0.40	٧	$I_F = 20mA, I_C = 1.8mA$
H22A4	V _{CE(SAT)}	_	V1.	0.40	. V	$I_F = 30 \text{mA}, I_C = 1.8 \text{mA}$
Turn-On Time	t _{on}	_	8	_	μS	$V_{cc} = 5V, I_F = 30 \text{ mA}, R_L = 2.5 \text{ K}$
Turn-Off Time	t _{off}		50	_	μS	$V_{cc} = 5V$, $I_{c} = 30$ mA, $R_{c} = 2.5$ K







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